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(54) Title: METHOD FOR PRODUCING CARBON NANOTUBES AND/OR NANOFIBRES

(57) Abstract: A method for producing aligned carbon nanotubes and/or nanofibres comprises providing finely divided substrate particles having substantially smooth faces with radii of curvature of more than 1  $\mu$ m and of length and breadth between 1  $\mu$ m and 5 mm and having catalyst material on their surface and a carbon-containing gas at a temperature and pressure at which the carbon-containing gas will react to form carbon when in the presence of the supported catalyst, and forming aligned nanotubes and/or nanofibres by the carbon-forming reaction.

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#### Method for Producing Carbon Nanotubes and/or Nanofibres

The present invention relates to a method of producing

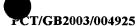
5 carbon nanotubes and/or nanofibres, and to nanotubes and/or nanofibres so produced.

Carbon nanotubes are tubular fullerenic structures which may be single-walled or multi-walled. Carbon nanofibres are fullerenic nanostructures in which the graphitic layers are not tubular: for example, solid fullerenic cylinders or hollow cylindrical fullerenic structures wherein the fullerene net is not parallel to the cylinder axis.

15 Carbon nanotubes and nanofibres have remarkable mechanical and electrical properties and are being investigated for many potential applications. These materials have been produced previously by using various approaches, including laser or arc-discharge ablation of a carbon/catalyst mixture target. The materials are usually produced in an entangled state.

For larger scale synthesis, the most promising methods have been based on chemical vapour decomposition (CVD). In these methods, a carbon containing gas is decomposed at high temperature under the influence of a finely divided transition metal catalyst.

Large quantities of multi-walled nanotubes can be grown
using CVD by methods well known in the literature (H.G.
Tennant, US 5,165,909). However, this material, sometimes
termed 'cotton candy', is highly entangled, a characteristic



that reduces its utility in certain applications (for example, this material is not readily dispersible as a filler). In addition, nanotubes grown in this way do not have a clearly defined length and often have to be broken up into shorter sections using aggressive chemical treatments (e.g. boiling in concentrated nitric acid) in order to achieve a good dispersion (Shaffer). Particulate substrates have also been used as catalyst supports for growing entangled nanotubes (e.g. WO00/17102).

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WO00/73205 discloses a method for producing carbon nanotubes from carbon monoxide gas using silica-supported cobalt and molybdenum as a catalyst. The single-walled nanotubes produced are locally roughly aligned in bundles but each nanotube travels between different bundles and the material is thus entangled.

Multi-walled nanotubes have also been grown on nonparticulate substrates (usually quartz plates or furnace 20 tubes with diameters between 15 mm and 100 mm) in order to form aligned arrays, also known as 'carpets', 'forests', or 'grass' (e.g. Andrews). The process usually involves the thermal decomposition of ferrocene/toluene mixtures at 600-1000 °C although a variety of related feedstocks may be 25 used. By varying processing parameters such as time, temperature, and catalyst concentration it is possible to adjust the length, diameter, and packing density of the nanotubes formed within certain ranges (e.g. Singh). Aligned nanotubes have also widely been prepared on flat 30 substrates by using various types of plasma enhancement (for example microwave, radio-frequency or direct current) (e.g. Ren). Aligned nanotubes grown by thermal CVD often have a

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higher crystalline quality than their 'cotton candy' counterparts.

The present invention provides in a first aspect a method for producing aligned carbon nanotubes and/or nanofibres comprising providing finely divided substrate particles having substantially smooth faces with radii of curvature of more than 1 µm and of length and breadth between 1 µm and 5 mm having a catalyst material on their surface and a carbon-containing gas at a temperature and pressure at which the carbon-containing gas will react to form carbon when in the presence of the supported catalyst, and forming aligned nanotubes and/or nanofibres by the carbon-forming reaction.

15 At the nanometer scale (less than 100 nm), the surface may have a texture or roughness that stabilises metal catalyst clusters of suitable sizes for nanotube and/or nanofibre growth. The surface should be smooth over the order of size of catalyst material clusters.

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Preferably, the faces have radii of curvature of more than 10  $\mu m$ . More preferably, the substantially smooth faces are substantially flat.

25 Preferably, the catalyst material is dispersed in clusters on the surface of the substrate particles. More preferably, the catalyst material clusters are from 0.5 nm to 100 nm in dimension. Highly preferably, the catalyst material clusters are from 3 nm to 50 nm in dimension.

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Optionally, the substrate particles having catalyst material on their surface are prepared by depositing catalyst material on the surface of the substrate particles.

Metal or metal salts may be introduced onto the substrate particles by a range of treatments including electroless deposition, solvent drying, supercritical drying, sputtering, physical vapour deposition, or electroplating. Subsequent thermal and/or oxidising or reducing gas treatments may be used in converting a given salt to a metal or to a suitable precursor for thermal decomposition (see below). Continuous films may be broken up on thermal treatment to form suitable catalyst particles by a dewetting process.

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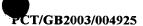
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Alternatively, the substrate particles having catalyst material on their surface may be prepared by providing finely divided substrate particles and a catalyst precursor material and decomposing the catalyst precursor material to form the catalyst material in the presence of the substrate particles such that the catalyst material is deposited on the substrate particles. In a preferred embodiment of the invention, the catalyst precursor material is decomposed while the substrate particles are in contact with the carbon-containing gas, for example within the main CVD furnace.

As a further alternative, the substrate particles having catalyst material on their surface may be prepared by providing finely divided substrate particles of a material that is decomposable to form catalyst material on the surface of non-catalyst substrate particles and decomposing

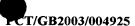


said material. Some perovskites are known to behave in this way (e.g. Liang).

Preferably, the length and breadth of the substrate particle faces are between 10  $\mu m$  and 500  $\mu m$ . If the particle is facetted, the majority of facets are preferably more than 25  $\mu m^2$  in area and most preferably wider than 2  $\mu m$  in each direction.

The substrate may be, by way of example, ceramic (silica or 10 alumina), mineral (mica), metallic (titanium), salt (sodium chloride, magnesium oxide, calcium oxide) or carbon-based. The substrate particles may be of graphite, aluminium or titanium. Preferably, the substrate particles are of silica, carbon, magnesium oxide, calcium oxide, or sodium chloride. 15 In the most straightforward case, the substrate particles are simply finely ground powders, such as silica or alumina, or drawn aluminosilicate fibres, or processed minerals such as mica. Other materials may be generated by a range of methods, known to those skilled in the art, such as 20 colloidal processing, spray-drying, hydrothermal processing, ball-milling extrusion and so on. Freshly prepared materials with uncontaminated surfaces (e.g. as obtained by prompt use of ball milled silica, milled using silica-based balls) are preferably used in order to obtain best results. 25 Preferably, the materials are used within a day of preparation.

Preferably, the substrate particles are anisotropic in order to provide a large surface area to volume ratio. More preferably, the substrate particles have one dimension



larger than the other two dimensions or the substrate particles have one dimension smaller than the other two dimensions.

5 Optionally, the substrates are coated with a buffer layer.

The buffer layer on the surface of the substrate particles serves either to support or enhance the catalyst particles or to isolate the growth process from the underlying material. As an example, such an approach could be useful when using a substrate that is convenient to remove after the growth reaction but which has a relatively high solubility for the catalyst metal (such as a magnesium oxide/nickel system). Such a buffer layer may be introduced by deliberate treatment (Sun) or may arise naturally (e.g. the oxide layer on titanium particles).

Preferably, the catalyst material is a transition metal, an alloy of two or more thereof, a compound of a transition metal or a mixture of two or more compounds of transition 20 metals. Particularly suitable are the Group VIB chromium (Cr), molybdenum (Mo), tungsten (W) or Group VIIIB transition metals, e. g., iron (Fe), cobalt (Co), nickel (Ni), ruthenium (Ru), rhodium (Rh), palladium (Pd), osmium (Os), iridium (Ir) and platinum (Pt) or mixtures thereof.

25 Metals from the lanthanide and actinide series may also be used. More preferably, the transition metal is iron, cobalt, molybdenum or nickel or mixtures thereof.

Preferably, the catalyst precursor is a transition metal carbonyl, or a transition metal cyclopentadienyl compound.

More preferably, the catalyst precursor is ferrocene, nickelocene, cobaltocene, iron pentacarbonyl or nickel



tetracarbonyl. The catalyst precursor compound may provide the carbon-containing gas, for example where ferrocene is used to provide iron catalyst and cyclopentadiene carboncontaining gas.

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Preferably, the carbon containing gas is carbon monoxide, an oxygen containing organic compound or a hydrocarbon, or a mixture of two or more thereof. More preferably, the carbon containing gas is carbon monoxide, benzene, toluene, xylene, cumene, ethylbenzene, naphthalene, phenanthrene, anthracene, methane, ethane, propane, hexane, ethylene, propylene, acetylene, formaldehyde, acetaldehyde, acetone, methanol, ethanol or a mixture of two or more thereof. In preferred embodiments, the carbon-containing compound is toluene, xylene or benzene. It is of course only required that the reactant be gaseous under the reaction conditions.

Optionally, one or more boron and/or nitrogen containing compound is provided in addition to the carbon containing gas. It has been shown in flat substrate studies that boron or nitrogen can be introduced into the carbon lattice (Terrones), by using boron or nitrogen containing species in the feedstock for the CVD reaction. Accordingly, it is possible to grow large volumes of such 'doped' materials using this invention by the addition of suitable species, such as ammonia, pyridine, aniline, borazine, borane, phthalocyanines, to the feedstock.

Optionally, one or more promoter compounds is provided in addition to the carbon containing gas. Promoters aid the catalytic selectivity or reactivity. These agents may be added as the catalyst is formed or during growth of the



nanotubes and/or nanofibres. For example, thiophene may be added to encourage the production of herringbone fibres or single-walled nanotubes (Singh, Zhu).

Optionally, a diluent gas is provided mixed with the carbon containing gas. The diluent is preferably an inert gas, e.g. argon. The carbon-containing gas may also be mixed with non carbon-containing gases that play no direct role in the carbon-forming reaction but which play a contributory role, for instance by reacting with amorphous carbon as it is formed (as a by-product) and so keeping the reaction sites on the catalyst clean and available for nanotube formation. Gases which may be mixed with the carbon-containing gas include argon, hydrogen, nitrogen, ammonia, or helium.

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The substrate particles may be introduced into the CVD reactor batchwise, or added to the furnace continuously either using standard powder handling techniques or by carrying in a suitable gas (see PCT/GB02/02239). Preferably, substrate particles are provided and product particles are removed from a reaction vessel in a continuous fashion.

Once introduced to the furnace, the substrate particles may sit in a fixed bed, a fluidised bed, or be carried within the gas flows in the system.

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Preferably, the method described above further comprises the step of recovering the aligned nanotubes and/or nanofibres.

Preferably, gaseous effluent from the reaction is recycled 30 with or without clean up.



Suitably, formation of the nanotubes and/or nanofibres takes place at a temperature of from 650 °C to 1250 °C, e.g. 650 °C to 850 °C. Preferred gas pressures are from 0.1 to 50 bar A, preferably from 0.5 to 5 bar A, more preferably 1 to 2 bar A. The ratio of catalyst metal to carbon fed to the reaction zone is preferably less than 1:100, e.g. 1:100 to 1:500.

In a second aspect, the invention relates to finely divided substrate particles having substantially smooth faces with radii of curvature of more than 1 µm and of length and breadth between 1 µm and 5 mm with a catalyst material on the surface of the substrate particles and with aligned carbon nanotubes and/or nanofibres on the surface of the substrate particles. The nanotube and/or nanofibre coated substrate particles may be used directly (with either or both components contributing to a desired active or passive functionality).

Alternatively, the nanotubes or nanofibres may be removed from the substrate by dissolution of the substrate (e.g. hydrogen fluoride treatment of silica, or hydrothermal treatment of sodium chloride) or by dissolution of the catalyst or buffer layers (e.g. iron in dilute hydrochloric acid). The now disconnected nanotubes and/or nanofibres and substrates may be conveniently separated by filtration or sedimentation. In particular the disconnected materials may be placed in a medium of intermediate density such that the substrate particles sink and the nanotubes and/or nanofibres rise (or vice versa). After separation, the substrate particles may be reused.



In a third aspect, the invention relates to nanotubes and/or nanofibres produced by a method as described above.

Preferably, the nanotubes and/or nanofibres are separated

from the substrate particles by partial or complete dissolution of the substrate particles or catalyst materials.

The invention will be further described with reference to the following Example and with reference to the Figures, in which:

Figure 1 shows an SEM image of aligned nanotubes grown on quartz substrate at ~ 700 °C for 90 minutes.

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Figure 2 shows a Raman spectrum taken from the nanotubes grown at 700 °C taken using a 514 nm excitation laser.

Figure 3 shows TGA on nanotubes grown at 700 °C for 90 minutes, 750 ml min $^{-1}$  Ar: $H_2$  flow rate and at a feed rate 1.2 20 ml hr $^{-1}$  of the solution.

#### Example

A solution containing 2 wt% of ferrocene dissolved into toluene was prepared. 100 mg of high surface area quartz powder was prepared by ball milling. Milling time was 2 hours using alumina ball-bearings. The silica broke up into flakes approximately 10 to 40 µm in diameter and around 1 µm thick. The ground silica was sorted with a 75 µm sieve. The fine powder was then placed into a horizontal tube furnace



(internal diameter 14 mm, length 90 cm) and heated to 700  $^{\circ}\text{C.}$  The solution was sprayed into the furnace at 1.2 ml  $\text{hr}^{-1}$ using a dry argon-hydrogen atmosphere for 90 minutes. The ratio of argon to hydrogen was 14:1 with a total gas flow rate of  $750 \text{ ml min}^{-1}$ . The products were characterised by 5 electron microscopy, both scanning (SEM) and high-resolution transmission electron microscopy (HRTEM), and Raman spectroscopy and Thermogravimetric analysis (TGA). From Figure 1 it can be seen that the nanotubes are in abundance, high purity, and aligned with constant lengths. The 10 nanotubes are mainly in the bundled form growing perpendicular to the surface of the support. The average diameters of the nanotubes were 27  $\pm$  2.7 nm determined using TEM.

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In Figure 2 the quality of the material based upon the relative intensity of the peak at ~ 1350 cm<sup>-1</sup> to ~ 1580 cm<sup>-1</sup> indicates that the nanotubes contain few defects. TGA (Figure 3) indicates that approximately 40 % of the weight loss was due to the nanotubes. The remaining powder was iron oxide supported on quartz. The average weight loss from TGA was ~ 32.5 %.

The advantages of the technique of the Example for large scale production of carbon nanotubes are summarised as follows:

 Low production cost: the raw materials involved for forming the support, catalyst and carbon feedstock are cheap and readily available in large quantities.

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- 2. The method results in high volumes and high yield of good quality pure nanotubes, and can readily be scaled up to an industrial level.
- 3. Characteristics such as nanotube/nanofibre diameter and length can be manipulated by the growth process.

The disadvantage of known flat substrate methods of production compared with the method of the Example is that the ratio between the growing surface area and volume of support is low as a result of the geometry of the plates. Because the growth is confined to a macroscopic surface the total volumetric yield of product is low.

The disadvantage of the method of WO00/73205 compared with

15 the method of the Example is that aligned, non-entangled nanotubes are not produced. This is apparently because the substrate particles used in that method do not have the required characteristics.

Whilst the applicants do not wish to be bound by this theory, it is believed that during growth the aligned nanotube or nanofibre arrays grow from all sides of the substrate particle, leading to a large volume of carbon product. During growth the substrate particles move apart in order to accommodate the growing nanotubes.



References:

Andrews, R., Jacques, D., Rao, A.M., Derbyshire, F., Qian, D., Fan, X., Dickey, E.C., and Chen, J., Continuous production of aligned carbon nanotubes: a step closer to commercial realization. Chemical Physics Letters, 1999.

303(5-6): p. 467-474.

Ren, Z.F., Huang, Z.P., Xu, J.W., Wang, J.H., Bush, P.,

Siegal, M.P., and Provencio, P.N., Synthesis of large arrays
of well-aligned carbon nanotubes on glass. Science, 1998.

282(5391): p. 1105-1107.

Liang, Q., Tang, S.H., Gao, L.Z., Chen, Z.Y., Zhang, B.L.,

Yu, Z.L., A study on production of carbon nanotubes by

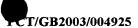
decomposition of CH<sub>4</sub> over the pre-reduced catalysts LaNiO<sub>3</sub>,

La<sub>4</sub>Ni<sub>3</sub>O<sub>10</sub>, La<sub>3</sub>Ni<sub>2</sub>O<sub>7</sub> and La<sub>2</sub>NiO<sub>4</sub>, Acta Chim. Sin., 2001, 59, 8,

p. 1236-1240.

- 20 Sun, X., Stansfield, B., Dodelet, J.P., Desilets, S., Growth of carbon nanotubes on carbon paper by ohmically heating silane-dispersed catalytic sites, Chem. Phys. Lett. 363 (2002) 415-421.
- 25 Production of aligned carbon nanotubes by the CVD injection method, Singh C, Shaffer M, Kinloch I, and Windle A, Physica B, Vol 323, No. 1-4, 339-340, 2002

Shaffer MSP, Fan X, Windle AH, Dispersion and packing of carbon nanotubes, Carbon, 1998, Vol.36, No.11, 1603-1612



Terrones, M., Benito, A.M., MantecaDiego, C., Hsu, W.K., Osman, O.I., Hare, J.P., Reid, D.G., Terrones, H., Cheetham, A.K., Prassides, K., Kroto, H.W., and Walton, D.R.M., Pyrolytically grown BxCyNz nanomaterials: Nanofibres and nanotubes. Chemical Physics Letters, 1996. 257(5-6): p.576-582.

Terrones, M., Redlich, P., Grobert, N., Trasobares, S., Hsu, W.K., Terrones, H., Zhu, Y.Q., Hare, J.P., Reeves, C.L.,

10 Cheetham, A.K., Ruhle, M., Kroto, H.W., and Walton, D.R.M., Carbon nitride nanocomposites: Formation of aligned CxNy nanofibers. Advanced Materials, 1999. 11(8): p. 655

Singh, C., Quested, T., Boothroyd, C., Thomas, P., Kinlock,

I., Abou Kandil, A., Windle, A.H., Synthesis and

characterisation of carbon nanofibres produced by the

floating catalyst method, J. Phys. Chem. B., 2002, 106, p.

10915-10922.

20 Zhu, H.W., Xu, C.L., Wu D.H., Wei B.Q., Vajtai R., Ajayan P.M., Direct synthesis of single-walled carbon nanotube strands, Science, 2002, 296, 884-886



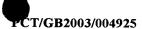
#### Claims:

A method for producing aligned carbon nanotubes and/or nanofibres comprising providing finely divided substrate particles having substantially smooth faces with radii of curvature of more than 1 μm and of length and breadth between 1 μm and 5 mm and having catalyst material on their surface and a carbon-containing gas at a temperature and pressure at which the carbon-containing gas will react to form carbon when in the presence of the supported catalyst, and forming aligned nanotubes and/or nanofibres by the carbon-forming reaction.

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- 2. A method as claimed in Claim 1, wherein the faces have radii of curvature of more than 10  $\mu m\,.$
- 3. A method as claimed in either one of the preceding claims, wherein the substantially smooth faces are substantially flat.
- A method as claimed in any one of the preceding claims wherein the catalyst material is dispersed in clusters on the surface of the substrate particles.
  - 5. A method as claimed in Claim 4, wherein the catalyst material clusters are from 0.5 nm to 100 nm in dimension.

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- 6. A method as claimed in Claim 5, wherein the catalyst material clusters are from 3 nm to 50 nm in dimension.
- 7. A method as claimed in any preceding claim, wherein the substrate particles having catalyst material on their surface are prepared by depositing catalyst material on the surface of the substrate particles.
- 8. A method as claimed in Claim 7, wherein the catalyst
  10 material is deposited by electroless deposition,
  solvent drying, supercritical drying, sputtering,
  physical vapour deposition or electroplating.
- 9. A method as claimed in any one of Claims 1 to 6,
  wherein the substrate particles having catalyst
  material on their surface are prepared by providing
  finely divided substrate particles and a catalyst
  precursor material and decomposing the catalyst
  precursor material to form the catalyst material in the
  presence of the substrate particles such that the
  catalyst material is deposited on the substrate
  particles.
- 10.A method as claimed in Claim 9, wherein the catalyst precursor material is decomposed while the substrate particles are in contact with the carbon-containing gas.
- 11.A method as claimed in any one of Claims 1 to 6, wherein the substrate particles having catalyst material on their surface are prepared by providing finely divided substrate particles of a material that is decomposable

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to form catalyst material on the surface of non-catalyst substrate particles and decomposing said material.

- 12.A method as claimed in any preceding claim, wherein the length and breadth of the substrate particle faces are between 10 μm and 500 μm.
- 13.A method as claimed in any preceding claim, wherein the substrate particles are of silica, alumina, carbon,
  10 mica, magnesium oxide, calcium oxide, sodium chloride, pure metal or aluminosilicate or a mixture of two or more thereof.
- 14.A method as claimed in Claim 13, wherein the substrateparticles are of graphite, aluminium or titanium.
  - 15.A method as claimed in any preceding claim, wherein the substrate particles are anisotropic.
- 20 16.A method as claimed in Claim 15, wherein the substrate particles have one dimension larger than the other two dimensions or wherein the substrate particles have one dimension smaller than the other two dimensions.
- 25 17.A method as claimed in any one of preceding claims where the substrates are coated with a buffer layer.
  - 18.A method as claimed in any preceding claim, wherein the substrate is freshly prepared.

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- 19.A method as claimed in Claim 18, wherein the substrate is prepared by colloidal processing, spray-drying, hydrothermal processing, or ball-milling.
- 5 20.A method as claimed in any preceding claim, wherein the catalyst material is a transition metal, an alloy of two or more thereof, a compound of a transition metal or a mixture of two or more compounds of transition metals.
- 10 21.A method as claimed in Claim 20, wherein the transition metal is iron, cobalt, molybdenum or nickel.
  - 22.A method as claimed in Claim 9 or Claim 10, wherein the catalyst precursor is a transition metal carbonyl, or a transition metal cyclopentadienyl compound.
  - 23.A method as claimed in Claim 22, wherein the catalyst precursor is ferrocene, nickelocene, cobaltocene, iron pentacarbonyl or nickel tetracarbonyl.
  - 24.A method as claimed in any preceding claim, wherein the carbon containing gas is carbon monoxide, an oxygen containing organic compound or a hydrocarbon, or a mixture of two or more thereof.
- 25.A method as claimed in Claim 24, wherein the carbon containing gas is carbon monoxide, benzene, toluene, xylene, cumene, ethylbenzene, naphthalene, phenanthrene, anthracene, methane, ethane, propane, hexane, ethylene, propylene, acetylene, formaldehyde, acetaldehyde, acetone, methanol, ethanol or a mixture of two or more thereof.



- 26.A method as claimed in any one of the preceding claims wherein one or more boron and/or nitrogen containing compound is provided in addition to the carbon containing gas.
- 27.A method as claimed in any one of the preceding claims, wherein one or more promoter compounds is provided in addition to the carbon containing gas.

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- 28.A method as claimed in Claim 27, wherein the promoter compound is thiophene.
- 29.A method as claimed in any one of the preceding claims,
  wherein a diluent gas is provided mixed with the carbon containing gas.
  - 30.A method as claimed in any preceding claim, wherein the substrate particles are reacted within a fluidised bed.

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31.A method as claimed in any preceding claim, wherein substrate particles are provided and product particles are removed from a reaction vessel in a continuous fashion.

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- 32.A method as claimed in any preceding claim, further comprising the step of recovering the aligned nanotubes and/or nanofibres.
- 30 33.A method as claimed in any one of the preceding claims, wherein gaseous effluent from the reaction is recycled with or without clean up.

34. A method as claimed in any preceding claim, wherein the reaction takes place at a temperature between 650  $^{\circ}\text{C}$  and 1250  $^{\circ}\text{C}$ .

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- 35. Finely divided substrate particles having substantially smooth faces with radii of curvature of more than 1  $\mu m$  and of length and breadth between 1  $\mu m$  and 5 mm with a catalyst material on the surface of the substrate particles and with aligned carbon nanotubes and/or nanofibres on the surface of the substrate particles.
- 36. Carbon nanotubes and/or nanofibres produced by a method as claimed in any one of the preceding claims.

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37. Nanotubes and/or nanofibres as claimed in Claim 36, wherein the nanotubes and/or nanofibres are separated from the substrate particles by partial or complete dissolution of the substrate particles or catalyst materials.

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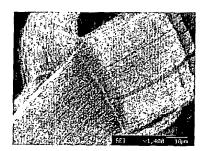


Figure 1

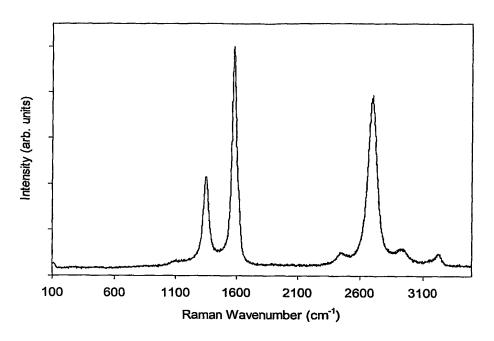


Figure 2

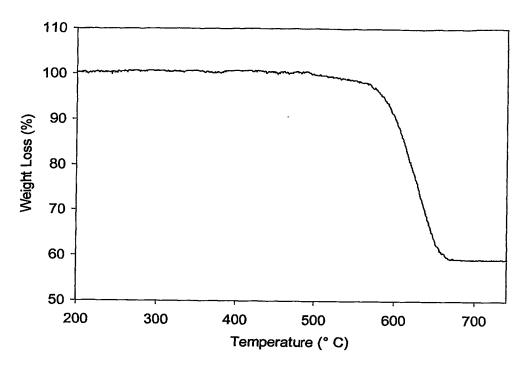


Figure 3



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INTERNATIONAL SEARCH REPORT	PCT/up U3/04925
A. CLASSIFICATION OF SUBJECT MATTER IPC 7 C01B31/02	
According to International Patent Classification (IPC) or to both national classification and IPC  B. FIELDS SEARCHED	
Minimum documentation searched (classification system followed by classification symbols) IPC 7 C01B	

Documentation searched other than minimum documentation to the extent that such documents are included in the fields searched

Electronic data base consulted during the international search (name of data base and, where practical, search terms used)

INSPEC, EPO-Internal, WPI Data, PAJ, CHEM ABS Data

C. DOCUM	ENTS CONSIDERED TO BE RELEVANT		
ategory °	Citation of document, with Indication, where appropriate, of	the relevant passages	Relevant to claim No.
<b>(</b>	WO 00 17102 A (SMALLEY RICHAR RICE WILLIAM M (US); SMITH KE HAFNE) 30 March 2000 (2000-03 cited in the application claims 1-10,12,15 page 18, line 31 -page 19, lipage 12, line 12 - line 14 page 14, line 30 -page 16, lipage 8, line 26 -page 10, line	N (US); -30) ne 2 ne 8	1-8,16, 20,21, 24,25, 32-37
		e 23 -/	11,26-28
<u> </u>	er documents are listed in the continuation of box C.	X Patent family members are	listed in annex.
A" docume conside E" earlier d filing da	egories of cited documents:  Int defining the general state of the art which is not extend to be of particular relevance ocument but published on or after the international steel the country of the cou	"T" later document published after the or priority date and not in conflicted to understand the principle invention  "X" document of particular relevance cannot be considered novel or involve and provider of particular relevance.	ct with the application but e or theory underlying the e; the claimed invention

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Date of the actual completion of the international search  25 February 2004	Date of mailing of the International search report  08/03/2004
Name and mailing address of the ISA  European Patent Office, P.B. 5818 Patentlaan 2  NL - 2280 HV Rijswijk  Tel. (+31-70) 340-2040, Tx. 31 651 epo nl,  Fax: (+31-70) 340-3016	Authorized officer  Rigondaud, B



# INTERNATIONAL SEARCH REPORT

Internal Application No PCT/up 03/04925

passages Relevant to claim No.  REPARED 11 VSKITE
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ER 01-02),
D CXNY - 6-02),
27,28 ethod" OCT.
1,4,5,7, 8,13
1-3,9, 10,13, 15,20, 21,32, 34-37



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C.(Continuation) DOCUMENTS CONSIDERED TO BE RELEVANT Citation of document, with indication, where appropriate, of the relevant passages Relevant to claim No. P,X SINGH C ET AL: "Towards the production of 1-3,10, 12,13, large-scale aligned carbon nanotubes"
CHEMICAL PHYSICS LETTERS, 6 MAY 2003,
ELSEVIER, NETHERLANDS, 15, 19-25, vol. 372, no. 5-6, pages 860-865, XP002271360 29,34-36 ISSN: 0009-2614 the whole document

Form PCT/ISA/210 (continuation of second sheet) (July 1992)



hation on patent family members

Internat Application No PCT/up 03/04925

Patent document cited in search report		Publication date		Patent family member(s)	Publication date
WO 0017102	A	30-03-2000	AU CA CN EP JP WO	6148499 A 2344180 A1 1334781 T 1115655 A1 2002526361 T 0017102 A1	10-04-2000 30-03-2000 06-02-2002 18-07-2001 20-08-2002 30-03-2000
WO 0030141	A	25-05-2000	US EP JP WO US	6232706 B1 1131838 A1 2002530805 T 0030141 A1 2001019238 A1	15-05-2001 12-09-2001 17-09-2002 25-05-2000 06-09-2001

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